

Positioning electro-optic polymer modulators as an optical engine to extend data rate and low power performance for optical networking

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Safe harbor

The information in this presentation may contain forward-looking statements within the meaning of the Private Securities Litigation Reform Act of 1995. You can identify these statements by use of the words "may," "will," "should," "plans," "explores," "expects," "anticipates," "continue," "estimate," "project," "intend," and similar expressions. Forward-looking statements involve risks and uncertainties that could cause actual results to differ materially from those projected or anticipated. These risks and uncertainties include, but are not limited to, general economic and business conditions, effects of continued geopolitical unrest and regional competition, changes in technology and methods of marketing, delays in completing various engineering and manufacturing programs, changes in customer order patterns, changes in product mix, continued success in technological advances and delivering technological innovations, shortages in components, production delays due to performance quality issues with outsourced components, and various other factors beyond the Company's control.



- Takeaways
- Hybrid PICs
- EO polymer performance
- Foundry partnering
- Going fast...
- Summary





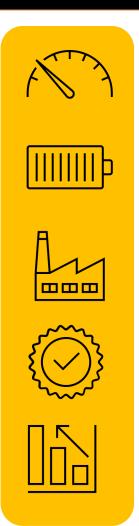
- We have unique polymers...
- Our technology is ultra-fast with stable materials...
- We are positioned to scale polymers to become ubiquitous...
- Polymers are foundry and pluggable TxRx compatible...



Polymer advantages



- Naturally very fast at switching light (material properties)
 - 2-3X existing solutions using modulators
- Naturally very low power consuming (material properties)
 - 10X lower power depending on device/architectural design
- Easily fabricated using CMOS/Silicon foundries
 - Process is standard and does not require special tool kits
 - Consistent, stable and reliable poling process
- EO Polymer has security of supply and scalable in vol
 - Material designed and sourced directly from LWLG
- Low-cost addition to integrated photonics platforms
 - Silicon photonics can be boosted in performance using hybrids

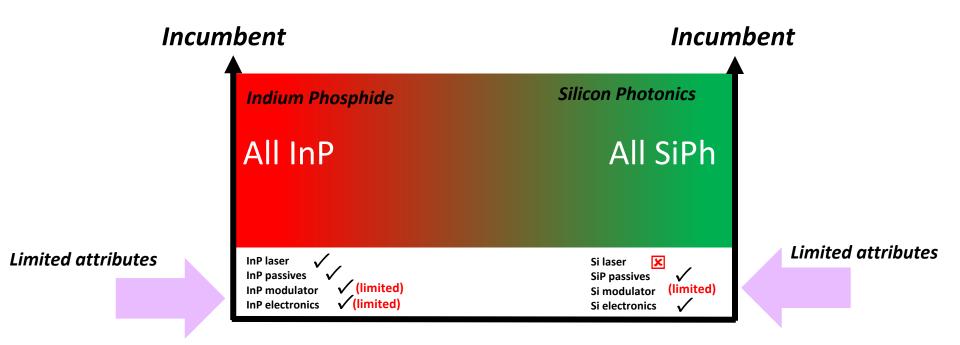




Fiber communications have 2 incumbent PICs, however...



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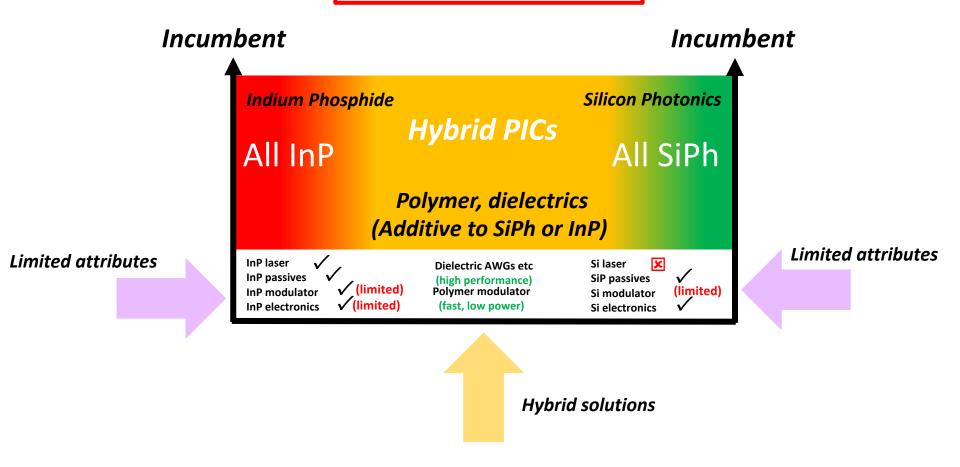


Source: LWLG NASDAQ: LWLG • 9

Hybrid PICs increase performance...



New hybrid PICs

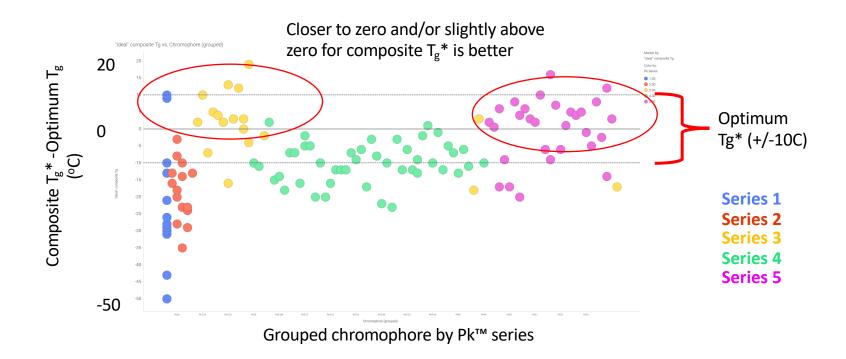


Hybrid PICs can boost performance of PICs

Source: LWLG • 10



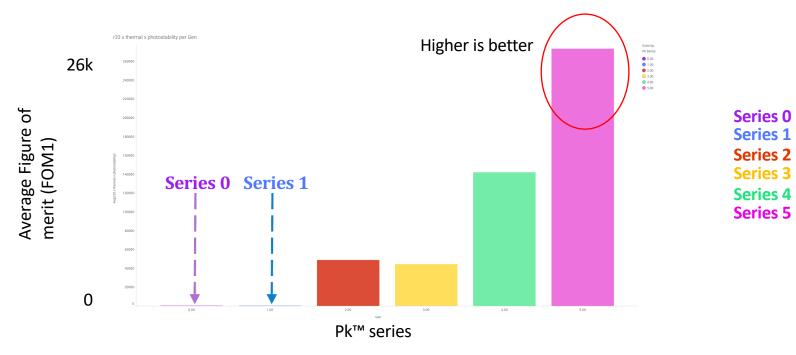
• T_g-Ideal T_g* vs Perkinamine™ chromophore (Pk™) Series



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^{*}Optimum Tg (glass transition temperature) is >> maximum operating temperature (but not so high that thermal disorder degrades poling efficiency)

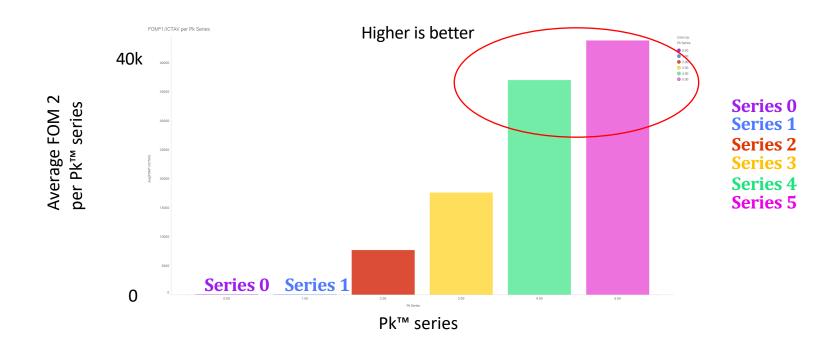
 Average FOM 1 (=r₃₃ x thermal stability x photostability) versus Pk™ series



 This Figure of Merit reflects the need for both high electrooptic activity and high stability for reliability

Commercial Figure of Merit 2 (FOM 2) by Pk™ series

• Commercial FOM 2 (=FOM 1 /abs $[T_g$ -Optimum T_g) includes in addition need for high T_g



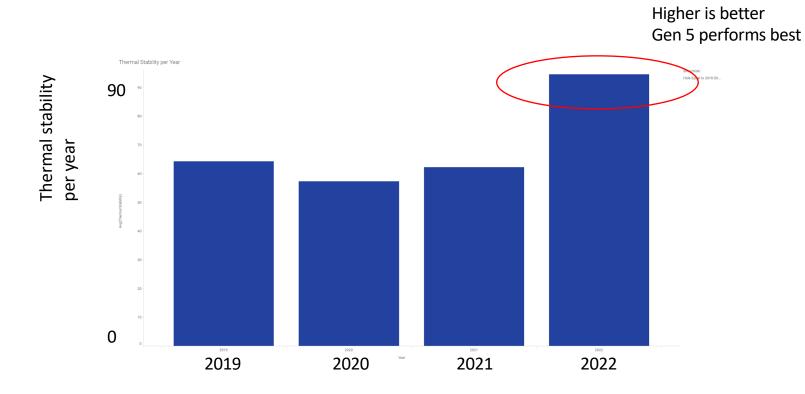
Pk™ series 5 more advanced and performs better compared to previous EO materials

Source: LWLG • NASDAQ: LWLG • 14

^{*}Optimum Tg (glass transition temperature) is >> maximum operating temperature (but not so high that thermal disorder degrades poling efficiency)

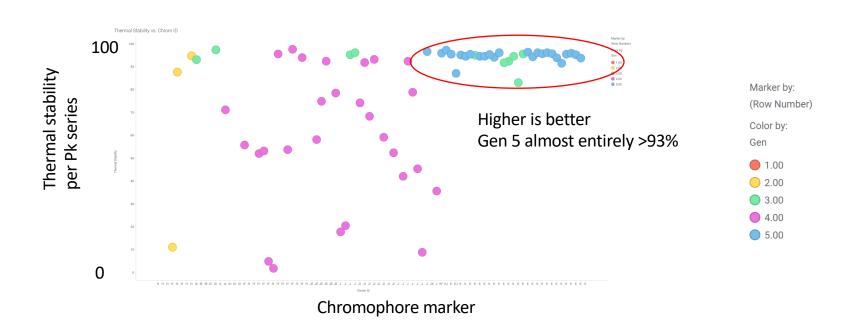
Commercial level thermal stability

Average thermal stability per year



Perkinamine™ thermal stability

Chromophore marker showing improvement in thermal stability



Source: LWLG • 16





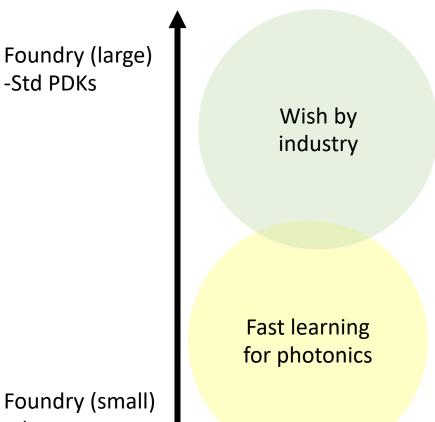


New technology	Foundry compatibility	Performance head room
Polymer (modulators)	Silicon, III-V	>100GHz many generations
Polymer plasmonic (modulators)	Silicon, III-V	>250GHz many generations
Polymer plasmonic rings (modulators)	Silicon, IIII-V	>250GHz many generations
Barium Titanate (modulators)	Silicon (?)	~70GHz (?)
Indium Phosphide (EAMs)	InP, Silicon with bonding	~ <70GHz
Silicon modulators	Silicon	~ <30-40GHz (doping)
Silicon Rings (modulators)	Silicon	~ <50-60GHz (thermal)
Thin Film Lithium Niobate (modulators)	Lithium Niobate Silicon ?	~ <70GHz (this generation)

Hybrid polymer enables economies of scale headroom







Fast cycle time

-Flex PDKs

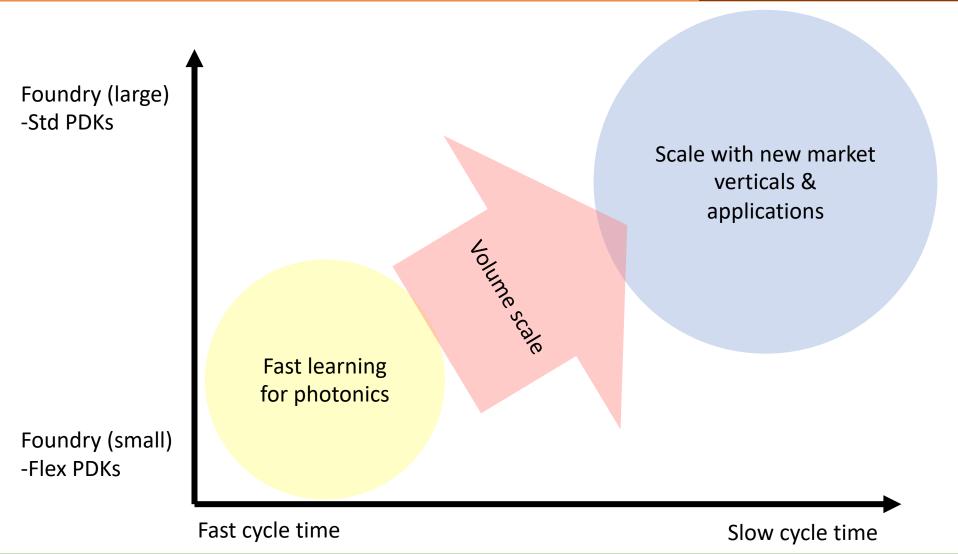
Slow cycle time

Photonics industry wants fast iterative learning for silicon photonics

NASDAQ: LWLG • Source: LWLG

Foundries have standard metrics





Foundries want silicon photonics to increase wafer throughput

Source: LWLG NASDAQ: LWLG • 20

Route to PDK acceptance



Foundry (large)
-Std PDKs

GLOBALFOUNDRIES FOUNDRY Sandia National unec CompoundTek SIEPIC LIGENTEC MOSIS

Foundry (small)
-Flex PDKs

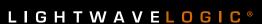
Fast cycle time

Slow cycle time

Foundries want silicon photonics to increase wafer throughput

Source: LWLG • 21

Partnering for success



- Partnering with foundries, packaging partners and module/transceiver partners to position LWLG for future high-volume production
- Partnering to integrate with polymer Process Development Kits (PDK) with foundries using standard fabrication techniques
- Technology evaluation & feedback
- Partnering for licensing the use of polymer materials that have been sourced, supplied and manufactured by LWLG
- Partnering for technology transfer of fabrication and device design to manufacturing facilities and foundries

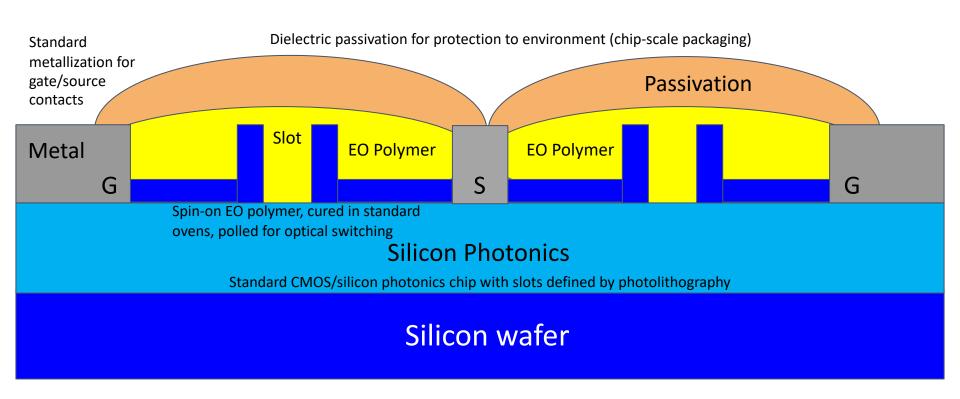




Partnering allows us to focus on our uniqueness, efficient use of capital, & to prepare for volume...

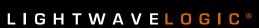


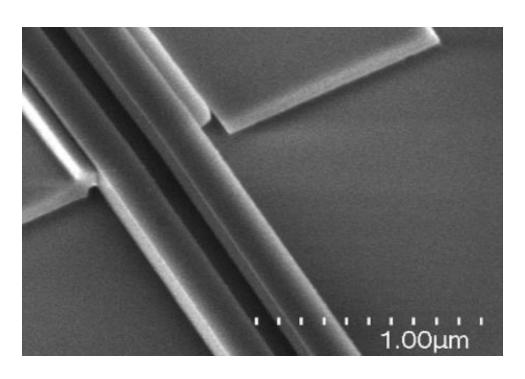
Standardized, consistent poling process with extremely high yields

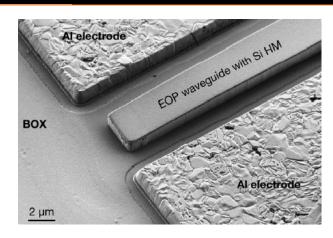


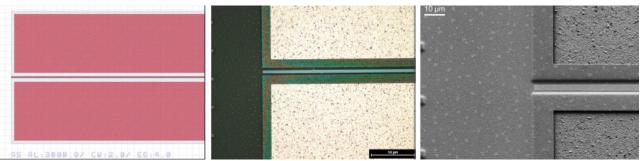
Standard silicon fabrication processes; standard silicon tools

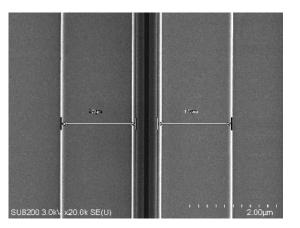












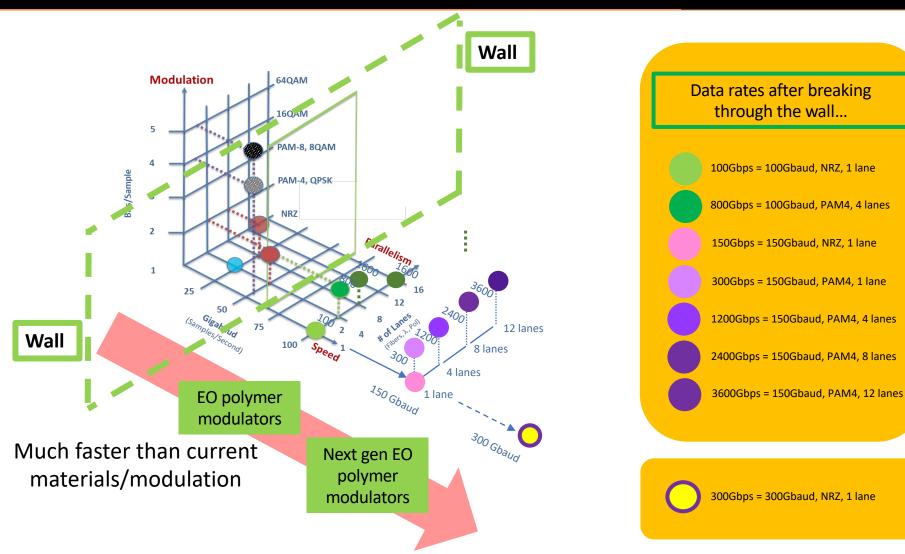
Standard silicon fabrication components...

Source: Lightwave Logic (LWLG) NASDAQ: LWLG ● 24



EO polymers break through the speed wall



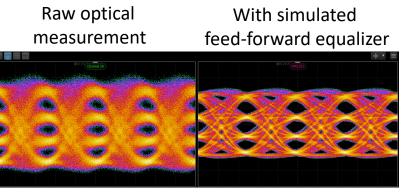


Ultra-fast speed...



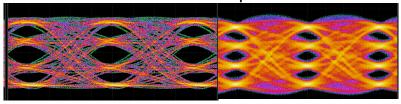


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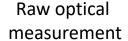


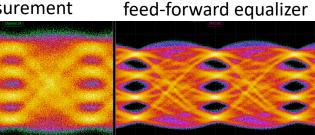
40 Gbaud PAM4 80 Gbps 2 V drive

With simulated feed-forward equalizer



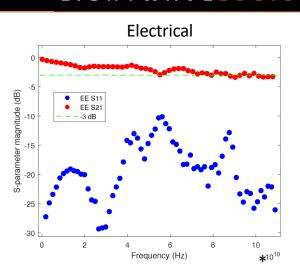
30 Gbaud PAM4 50 Gbaud PAM4 60 Gb/s 100 Gb/s 2 V drive 2 V drive

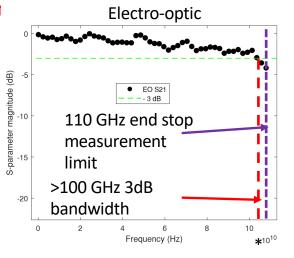




With simulated

50 Gbaud PAM4 100 Gb/s 2 V drive





Recent high-frequency S-parameter data from polymer modulators

Clean PAM4 eyes at 80Gbps with EO S21 >100GHz 3dB bandwidth

Source: LWLG NASDAQ: LWLG • 27





- •We have unique polymers...
- •Our technology is *ultra-fast* with stable materials...
- We are positioned to scale polymers to become *ubiquitous...*
- •Polymers are foundry and pluggable TxRx compatible...









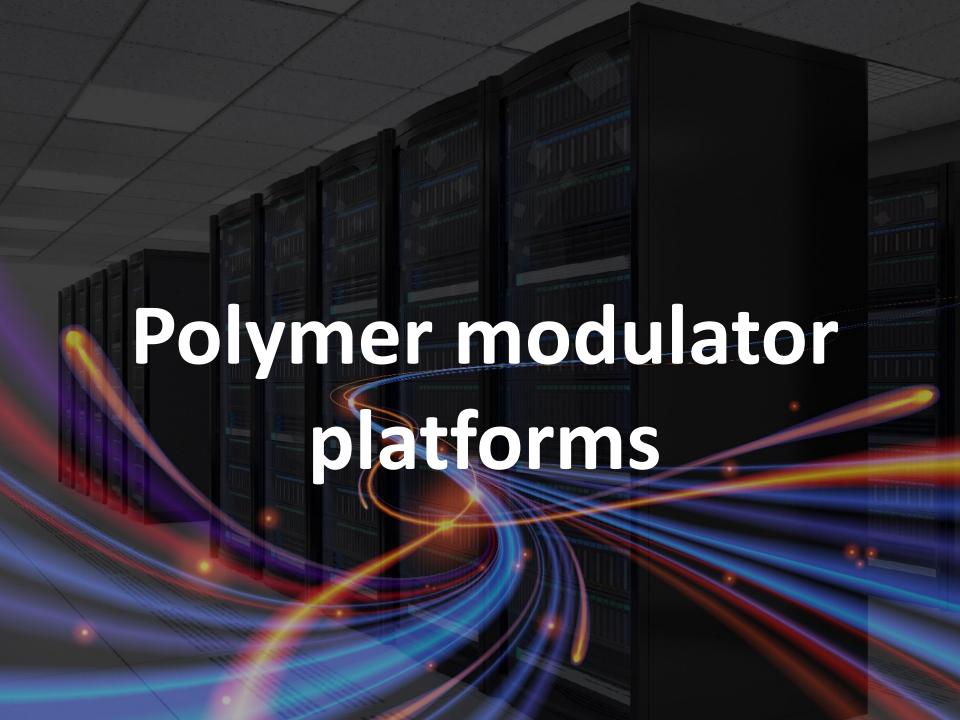


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1st Sept 2022: 1yr on NASDAQ

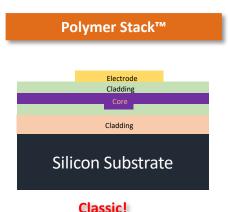
Source: NASDAQ: LWLG •



Natural integration with big foundries

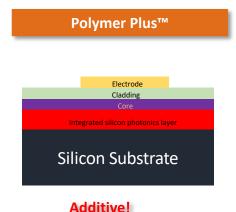


Additive to semiconductor platforms (SiPh, InP...) to enhance performance



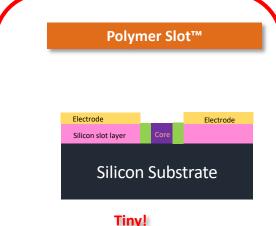
Polymer stack modulator

- 3-layer polymer stack waveguides
- Excellent high-speed performance and high stability.
- Standard fab equipment & methods



Simpler and easier to integrate

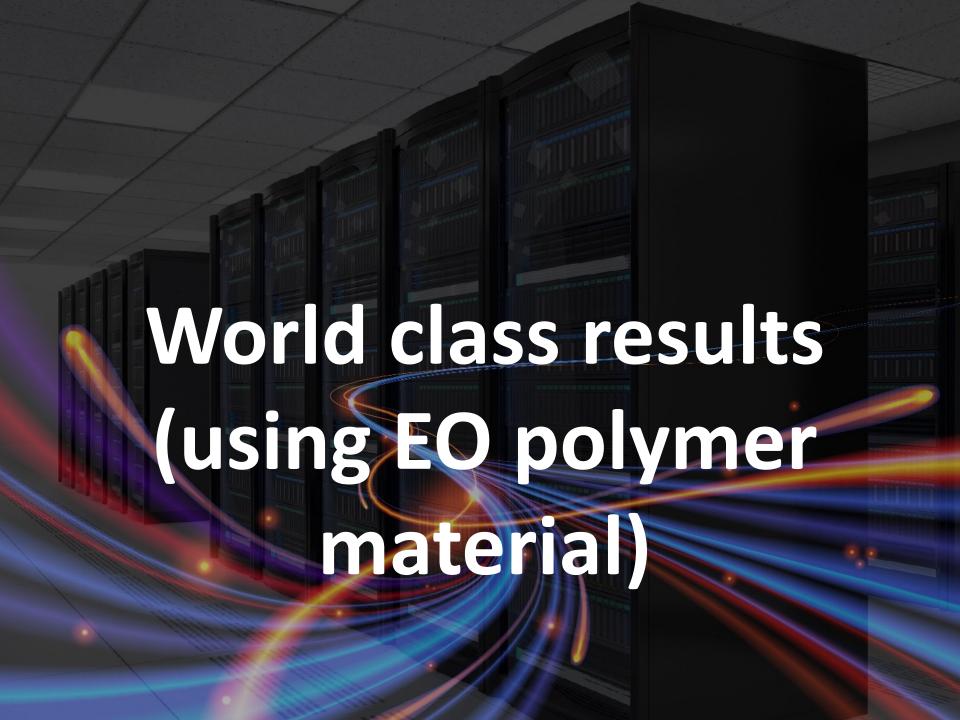
- Minimizing polymer layers for integration of modulator with other devices in Si (or other) PIC platform
- Natural integration with PDK of silicon foundries



Polymers in Si slot modulators

- Small size for highest integration levels
- Natural integration with PDK of silicon foundries

Turbo-charge your silicon photonics & integrated photonics with polymers...

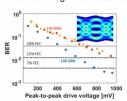


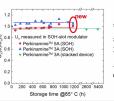
World record EO polymer results

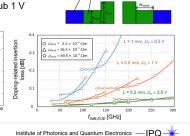


Summary

- Silicon-organic hybrid (SOH) integration can complement highly scalable silicon photonic circuits by efficient phase shifters
- RC bandwidth limitations can be overcome by multi-level doping
- PerkinamineTM materials offer thermal stability and high modulation efficiency
- Proof-of-concept demonstration: CMOS compatible sub 1 V drive voltage at 140 GBd PAM4

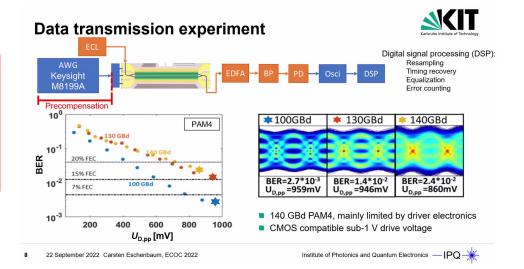






- Paper: 'Thermally stable SOH MZ modulator for 140Gbd PAM4 transmission with sub-1V drive signals
- Focus on stability

- World record performance electro-optic polymer silicon slot modulators
- Competitive low BER using FEC limits as per traffic rates



Silicon based electro-optic polymers and silicon photonics demonstrate world class speed of operation

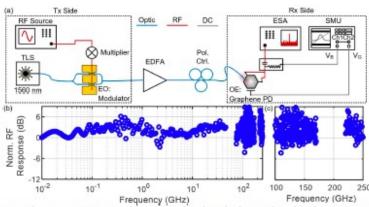


Fig. 3: Plasmonic-to-plasmonic EOE bandwidth. (a) Schematic of the setup to characterize the combined EOE bandwidth of the plasmonic racetrack modulator linked to the metamaterial graphene PD. (b) Measured normalized RF response of the system showing an EOE bandwidth of 250 GHz and (c) the response visualized from 100 to 250 GHz on a linear scale.

 World record performance electro-optic polymer plasmonic slot modulators working in a fully plasmonic link using LWLG EO-polymer material Paper: '>500GHz bandwidth graphene PD enabling highest-capacity plasmonicto-plasmonic' links

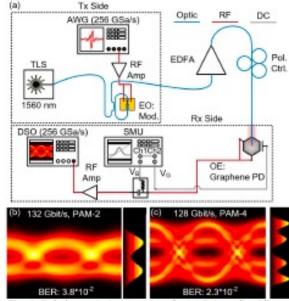


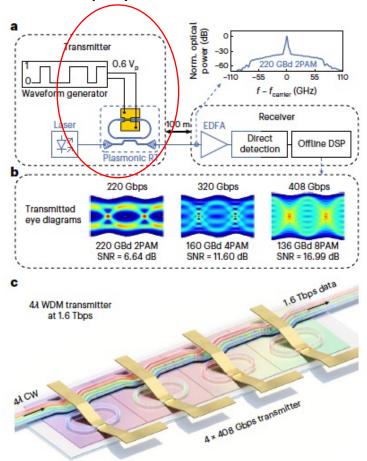
Fig. 4: Data transmission experiments. (a) Schematic of the used setup with the plasmonic racetrack modulator on the Tx side and the metamaterial GPD on the Rx side. (b,c) Optical eye diagram after offline DPS for 132 Gbit/s PAM-2 and 128 Gbit/s PAM-4 respectively.

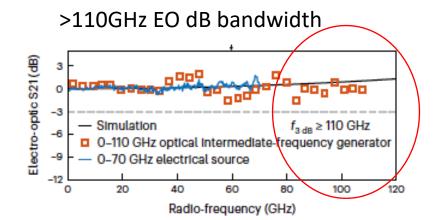
Electro-optic polymers outperform silicon modulators

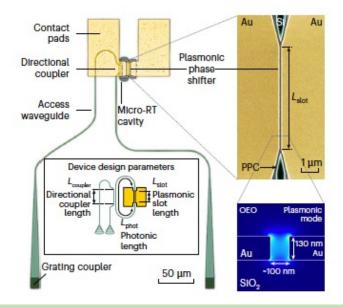
EO polymer plasmonic ring resonators

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0.6V and EO polymer material from LWLG







https://doi.org/10.1038/s41566-023-01161-9

Electro-optic polymers plasmonic ring resonators achieve >408Gbps with 0.6V and EP polymer material

World record performance of electro-optic polymer plasmonic ring resonator modulators compared to competitive ring resonators in silicon & TFLN

Table 1 | Literature overview of geometric, resonance and data transmission properties of published resonant modulators achieving >60 Gbps

Туре	Reference	Circumference (μm)	FSR (nm)	Q factor	V _π L (Vμm)	Electrical tuning (pm V ⁻¹)	Bandwidth (GHz)	Modulation format	Line rate (Gbps)	Driving voltage (V _p)
Plasmonic MRM	15	6	115	30	*	2,750	>115	2PAM	72	3.3
Si MRM 52	52	31	13	4,800	3,700	33	45	2PAM	60	0.8
								4PAM	100	1.25
Si MRM	53	31	20	3,000	*	33	55	4PAM	160	1.2
Si RT 54	54	60	7	5,600	8,000	26	79	2PAM	120	*
								4PAM	200	*
Si RT	24	60	7	5,600	8,000	26	67	DMT	301	*
Si MRM 55	55	38	11	4,200	5,300	*	77	2PAM	128	0.4
								4PAM	192	0.8
Si MRM	25	25	16	4,000	5,300	*	62	4PAM	240	0.9
TFLN Bragg 56	56	*	*	200,000	*	15	60	2PAM	100	0.9
								4PAM	100	0.9
Plasmonic RT Thi	This work	~90	7	~700	150	>178	176	2PAM	220	0.6
								4PAM	320	0.6
								8PAM	408	0.6

The plasmonic RTs presented in this work achieve 1.7 times improved data transmission speed (for intensity-modulated/PAM formats) with low 0.6 V_n driving voltage and a 2.2 times increased bandwidth over Si MRMs. TFLN, thin-film lithium niobate, Values denoted with * are not available.

https://doi.org/10.1038/s41566-023-01161-9